YUAN-CHUN LUO

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RESEARCH INTEREST

Nano-Electronics

EDUCATION

National Tsing Hua University (NTHU), Hsinchu, Taiwan

B.S., Electrical Engineering (EE)

Sep. 2014 - Jun. 2018

Overall GPA: 4.07/4.3 (3.93/4)

EXPERIENCE

Purdue University - ALD Group

Visiting Student

West Lafayette, IN Oct. 2018 - present

- Advisor: Professor Peide(Peter) Ye
- Apply germanium ferroelectric nanowire FETs as analog memories.

National Chiao Tung University (NCTU), DSML Group

Research Assistant

Hsinchu, Taiwan Dec. 2017 - Sep. 2018

- · Advisor: Professor Steve S. Chung
- Measured mobility and free energy in Ferroelectric FETs (FeFET)
- Extracted negative capacitance values, and minimize hysteresis in FeFETs (SSDM'18)
- Verified RF characteristics for FinFETs using the simulation tool, TCAD.

NTHU - THz Optoelectronic Devices Lab

Research Assistant

Hsinchu, Taiwan

Jun. 2017 - Jun. 2018

- · Advisor: Professor Shang-Hua Yang
- Designed THz plasmonic photomixers and antenna arrays using COMSOL and MATLAB.

NTHU - SSD LAB

Research Assistant

Hsinchu, Taiwan Sep. 2016 - Aug. 2017

- Advisor: Professor Ren-Shuo Liu.
- Achieved adaptive Convolutional Neural Networks using Python (VLSI-DAT'18).

PUBLICATION

An Experimental Method of Negative Capacitance(NC) Extraction in NC-gated-FinFET and Obtainment of near-free-**Hysteresis Characteristics by Body Effects**

- Y. C. Luo, E. R. Hsieh, C. J. Su, S. S. Chung, T. P. Chen, S. A. Huang, T. J. Chen, and O. Cheng;
- Applied Physics Letter (Submitted)

The Guideline on Designing a High-Performance NC MOSFET by Matching the Gate Capacitance and Mobility

- Y. C. Luo, F. L. Li, E. R. Hsieh, C. H. Liu, S. S. Chung, T. P. Chen, S. A. Huang, T. J. Chen, and O. Cheng;
- 2019 VLSI-TSA (Submitted)

New Experimental Approaches to Extracting Negative Capacitances of 14nm NC-FinFET in Exploration of Shortchannel & Body Effect to Achieve Free Hysteresis

- Y.-C. Luo, E. R. Hsieh, C. J. Su, S. S. Chung, T. P. Chen, S. A. Huang, T. J. Chen, and O. Cheng;
- 2018 SSDM Late News (Accepted, oral presentation)

DrowsyNET:Convolutional Neural Networks with Runtime Power-Accuracy Tunability Using Inference-Stage Dropout

- R. S. Liu, Y. C. Lo, Y.-C. Luo, C. Y. Shen, and C. J. Lee;
- 2018 VLSI-DAT (Accepted, oral presentation)

SELECTED HONOR AND AWARD

Champion, Contest of implementation

EE. NTHU. 2018

• Research project competition with more than 100 student competitors.

Runner up, Contest of implementation

EECS, NTHU, 2018

• Research project competition with more than 250 student competitors.

Excellent EECS student award

EECS. NTHU. 2017

Top 10% of all students in the college of EECS, NTHU.

Oversea exchange student scholarship

EE, NTHU, 2016

Awarded with USD 3100.

Outstanding academic achievement

EE, NTHU, 2015

Top 5% of all students.

LEADERSHIP & TEAMWORK

Student Association

Jun. 2016 - Jun. 2017 EE. NTHU

President

 Collaborated with Taiwan Semiconductor Manufacturing Company (TSMC) and arranged "mentor session," where students can ask for advice from managers in TSMC.

- Built a 20-student team to receive students and an advisor from City University of Hong Kong.
- Organized Christmas party for more than 200 students from four different departments.

SKILL

GRE score 331/340 (Q:170/170, V:161/170)

105/120 (R:29/30, L:29/30, S:22/30, W:25/30) TOEFL score

Cleanroom in NTHU: Nano-fabrication

(1) Certicifate of nano-fabrication training

Cleanroom in National Nano Device Laboratories (NDL) in Taiwan:

(2) License of E-gun and Chenmical Lab

(3) Training for E-beam system

Simulation Tools

COMSOL Multiphysics, and TCAD

Software Languages Hardware Languages C++, Matlab, and Python Verilog, Hspice, and Laker

SELECTED COURSE PROJECT

VLSI, Memory System Circuit Design Project

Jun. 2016

EE, NTHU

• Completed circuit design, pre-sim, layout, and post-sim of a memory system.

Semiconductor Microwave Electronic Devices, Term Paper

Jun. 2016

EE. NTHU

Investigated into silicon based RF semiconductor devices.

RELEVANT COURSES

Core Courses

ULSI Technology (A+, graduate level, nano-fabrication) Semiconductor Microwave Devices (A+, graduate level) Introduction to Solid-State Physics (A+)

Introduction to Solid-State Electronic Devices (A+)

Introduction to Integrated Circuit Design (A+)

Other Courses

Data Structure (A+) Electromagnetic Waves (A+) Feedback Control Systems (A+) Computer Architecture (A+) Modern Physics (A+)